

ENGLISH  
TRANSLATION  
OF INTERNATIONAL  
APPLICATION AS FILED

## DESCRIPTION

### INTERNAL CONDUCTOR CONNECTION STRUCTURE AND MULTILAYER SUBSTRATE

#### Technical Field

The present invention relates to an internal conductor connection structure and a multilayer substrate. In particular, it relates to an internal conductor connection structure capable of increasing a wiring density and to a multilayer substrate.

#### Background Art

In recent years, technologies for micromachining integrated circuits have dramatically advanced and, thereby, the number of external terminals of the integrated circuit has been increased, so that a pitch between external terminals has been reduced significantly. Recently, integrated circuits are mounted on ceramic substrates primarily by a flip chip bonding system. Pads for flip chip bonding are disposed on the surface of the ceramic substrate. Since the pitch between bonding pads must be reduced in accordance with a reduction of the pitch between external terminals of the integrated circuit, some methods have been proposed up to now.

For example, Patent Document 1 has proposed a ceramic wiring board provided with no bonding pad. The bonding pad is formed by a printing method or the like. When the number of bonding pads is increased, it becomes difficult to form pads by the printing method or the like. Even when bonding pads can be formed, the strength of bonding to the via conductor is weak, and the reliability cannot be ensured. Consequently, in the technology described in Patent Document 1, a ceramic multilayer substrate is produced by using a conductor paste having a firing shrinkage factor smaller than that of a ceramic green sheet and, thereby, a conductor layer (via conductor) in a through

hole is allowed to protrude as a bonding pad from the ceramic multilayer substrate. In this manner, printing of the bonding pad is avoided, the strength of bonding between the bonding pad and the via conductor is increased and, in addition, a reduction of pitch between bonding pads is realized. However, in Patent Document 1, no consideration is given to the connection structure of the via conductor and the line conductor in the inside of the ceramic multilayer substrate.

On the other hand, Patent Document 2 has proposed a monolithic ceramic electronic component in which a line conductor is provided with a connecting land, and a connection structure of a via conductor and the line conductor is improved. In the case where the via conductor and the line conductor are connected, a ceramic green sheet provided with the via conductor and a ceramic green sheet provided with the line conductor are aligned, and a laminate of the ceramic green sheets is prepared, followed by sintering. An occurrence of working error cannot be avoided in the formation of the via conductor and the line conductor on the ceramic green sheets, and it is difficult to avoid an occurrence of discrepancy between positions of the via conductor and the line conductor in the preparation of the laminate. Therefore, a poor connection between the via conductor and the line conductor tends to occur in the laminate. Consequently, in this technology, the line conductor is provided with a connecting land having a diameter larger than the outer diameter of the via conductor and, thereby, the occurrence of poor connection resulting from the above-described working loss and discrepancy between positions is prevented.

Patent Document 3 has proposed a method for manufacturing a multilayer ceramic substrate, in which the wiring density can be increased. In this case, as shown in Figs. 9(a) and (b), a connecting land 3 is formed on the lower end of a via conductor 2 disposed in a

multilayer ceramic substrate 1, and when via conductors 2 are adjacent to each other, their respective connecting lands 3 are formed in mutually different respective ceramic layers. The via conductors 3 are connected to line conductors 4 through the connecting lands 3. This technology has a commonality with the technology in Patent Document 2 in that the connecting land 3 is disposed.

Patent Document 1: Japanese Patent No. 2680443

Patent Document 2: Japanese Unexamined Patent Application  
Publication No. 2001-284811

Patent Document 3: Japanese Unexamined Patent Application  
Publication No. 11-074645

Disclosure of Invention

Problems to be Solved by the Invention

In the known technologies described in Patent Documents 2 and 3, since the line conductor or the via conductor has the connecting land, an occurrence of poor connection resulting from a discrepancy between positions of the via conductor and the line conductor, their respective working losses, and the like in the preparation of the ceramic substrate can be prevented by the connecting land. However, there is a problem in that, for example as shown in Fig. 9(a), since a connecting land 3 juts from a via conductor 2 toward an adjacent via conductor 2 side, a reduction of pitch between the via conductors 2 and 2 is hindered by the amount of jut. That is, when the pitch between the via conductors 2 and 2 is reduced, as shown in Fig. 10, the connecting land 3 and the adjacent via conductor 2 tend to be short-circuited, and delamination tends to occur during firing due to the difference in thermal expansion between the ceramic layer and the connecting land 3. Therefore, at least a clearance for preventing short circuit and delamination is required between the via conductors 2 and 2, and a jut dimension of the connecting land 3 is further added to this clearance, so that the connecting land hinders a reduction of

the pitch between the via conductors 2 and 2.

The present invention was made to overcome the above-described problems. Accordingly, it is an object of the present invention to provide an internal conductor connection structure capable of increasing a density of internal wiring in accordance with, for example, a reduction of the pitch between external terminals of an integrated circuit, as well as a multilayer substrate.

#### Means for Solving the Problems

An internal conductor connection structure according to Claim 1 of the present invention is characterized by connecting at least two via conductors adjacent to each other at a predetermined interval in an insulator substrate and line conductors disposed in the above-described insulator substrate, wherein one of the above-described via conductors includes a continuous via conductor disposed extending in a direction farther from the above-described other via conductor, and the above-described one of the via conductors is connected to the above-described line conductor through the above-described continuous via conductor.

The internal conductor connection structure according to Claim 2 of the present invention is characterized in that in the aspect described in Claim 1, a connecting portion of the above-described line conductor to the above-described continuous via conductor or a connecting portion of the above-described continuous via conductor to the above-described line conductor is disposed as a connecting land having an area larger than a connecting portion of the counterpart.

A multilayer substrate according to Claim 3 of the present invention is characterized by including a laminate in which a plurality of insulator layers are laminated, at least first and second via conductors individually extending inside the above-described laminate from positions adjacent to each other at a predetermined interval on one of main surfaces of the laminate, and a first line

conductor connected to the first via conductor, wherein the above-described first via conductor includes a first continuous via conductor disposed extending in a direction farther from the above-described second via conductor, and the above-described first via conductor is connected to the above-described first line conductor through the above-described first continuous via conductor.

The multilayer substrate according to Claim 4 of the present invention is characterized in that in the aspect described in Claim 3, a third via conductor is further included at predetermined distances from the first and second via conductors, the third via conductor extending inside the above-described laminate from the one of main surfaces of the above-described laminate, wherein the above-described second via conductor includes a second continuous via conductor disposed extending in a direction farther from both the above-described first and third via conductors, and the above-described second via conductor is connected to a second conductor line through the above-described second continuous via conductor.

The multilayer substrate according to Claim 5 of the present invention is characterized in that in the aspect described in Claim 4, the above-described first continuous via conductor and the second continuous via conductor are disposed in their respective insulator layers different from each other.

The multilayer substrate according to Claim 6 of the present invention is characterized in that in the aspect described in Claim 4 or Claim 5, the above-described first continuous via conductor and the second continuous via conductor are disposed in their respective insulator layers thinner than other insulator layers.

The multilayer substrate according to Claim 7 of the present invention is characterized in that in the aspect described in any one of Claim 4 to Claim 6, the above-described first continuous via conductor and the above-described second continuous via conductor

penetrate their respective insulator layers.

The multilayer substrate according to Claim 8 of the present invention is characterized in that in the aspect described in any one of Claim 4 to Claim 6, the above-described first continuous via conductor and the second continuous via conductor do not penetrate their respective insulator layers.

The multilayer substrate according to Claim 9 of the present invention is characterized in that in the aspect described in any one of Claim 3 to Claim 8, a connecting portion of the above-described first line conductor to the above-described first continuous via conductor or a connecting portion of the above-described first continuous via conductor to the above-described first line conductor is disposed as a connecting land larger than a connecting portion of the counterpart.

The multilayer substrate according to Claim 10 of the present invention is characterized in that in the aspect described in any one of Claim 4 to Claim 9, a connecting portion of the above-described second continuous via conductor to the above-described second line conductor or a connecting portion of the above-described second line conductor to the above-described second continuous via conductor is disposed as a connecting land larger than a connecting portion of the counterpart.

The multilayer substrate according to Claim 11 of the present invention is characterized in that in the aspect described in any one of Claim 3 to Claim 10, a surface electrode connected to each of the above-described via conductors is disposed on the above-described one of main surfaces.

The multilayer substrate according to Claim 12 of the present invention is characterized in that in the aspect described in any one of Claim 3 to Claim 10, an electronic component is mounted on the above-described one of main surfaces, and external terminal electrodes

of this electronic component are connected to the above-described first via conductor and the second via conductor exposed at the above-described main surface, without through any surface electrode.

The multilayer substrate according to Claim 13 of the present invention is characterized in that in the aspect described in any one of Claim 3 to Claim 12, the above-described one main surface side is configured to be connectable to a mother board.

The multilayer substrate according to Claim 14 of the present invention is characterized in that in the aspect described in any one of Claim 3 to Claim 13, the insulator layer is made of a low-temperature sinterable ceramic material.

The multilayer substrate according to Claim 15 of the present invention is characterized in that in the aspect described in any one of Claim 3 to Claim 14, each of the above-described via conductors and the line conductors is individually made of an electrically conductive material primarily containing silver or copper.

#### Advantages

According to the aspects described in Claim 1 to Claim 15 of the present invention, an internal conductor connection structure capable of increasing a density of internal wiring in accordance with, for example, a reduction of the pitch between external terminals of an integrated circuit, as well as a multilayer substrate, can be provided.

#### Brief Description of the Drawings

[Fig. 1] Fig. 1 is a schematic diagram showing an embodiment of an internal conductor connection structure of the present invention. Fig. 1(a) is a sectional view of a section taken along a line A-A shown in Fig. 1(b). Fig. 1(b) is a plan view of Fig. 1(a).

[Fig. 2] Each of Figs. 2(a) and (b) is an explanatory diagram for explaining a reduction of pitch of the internal conductor connection structure shown in Fig. 1 in comparison with that of a known connection structure.



[Fig. 3] Fig. 3 is a diagram showing an embodiment of a multilayer substrate of the present invention. Fig. 3(a) is a sectional view showing a key portion thereof, Fig. 3(b) is a plan view showing a connection structure of a via conductor and a line conductor, viewed from the via conductor side, and Fig. 3(c) is a plan view showing the connection structure of the via conductor and the line conductor, viewed from the line conductor side.

[Fig. 4] Fig. 4 is an exploded perspective view showing the multilayer substrate shown in Fig. 2 on a ceramic layer basis.

[Fig. 5] Fig. 5 is a diagram showing another embodiment of the multilayer substrate of the present invention. Fig. 5(a) is a sectional view showing a key portion thereof, Fig. 5(b) is a plan view showing a connection structure of a via conductor and a line conductor, viewed from the via conductor side, and Fig. 5(c) is a plan view showing the connection structure of the via conductor and the line conductor, viewed from the line conductor side.

[Fig. 6] Fig. 6 is a sectional view showing a key portion of another embodiment of the multilayer substrate of the present invention.

[Fig. 7] Fig. 7 is a sectional view showing a key portion of another embodiment of the multilayer substrate of the present invention.

[Fig. 8] Fig. 8 is a sectional view showing a key portion of another embodiment of the multilayer substrate of the present invention.

[Fig. 9] Fig. 9 is a diagram showing a known multilayer substrate. Fig. 9(a) is a sectional view showing a key portion thereof, and Fig. 9(b) is a plan view showing a connection structure of a via conductor and a line conductor, viewed from the via conductor side.

[Fig. 10] Fig. 10 is an explanatory diagram showing the state in which the via conductor and the line conductor in the multilayer substrate shown in Fig. 9 are short-circuited.

Reference Numerals

10 internal conductor connection structure

11 ceramic multilayer substrate (insulator substrate)  
12 first via conductor  
13 second via conductor  
15 first line conductor  
17 first continuous via conductor  
15A connecting land (connecting portion)  
30 ceramic multilayer substrate (multilayer substrate)  
31 laminate  
31A ceramic layer (insulator layer)  
31'A thin ceramic layer (thin insulator layer)  
32A first via conductor  
32B second via conductor  
32C third via conductor  
33A first line conductor  
34A first continuous via conductor  
35A connecting land  
36A connecting land  
40 integrated circuit  
50 mother board

#### Best Mode for Carrying Out the Invention

The present invention will be described below based on embodiments shown in Fig. 1 to Fig. 8.

#### FIRST EMBODIMENT

As schematically shown in, for example, Figs. 1(a) and (b), an internal conductor connection structure 10 of the present embodiment is configured as an internal conductor which including a plurality of via conductors (three units in Fig. 1), first, second, and third via conductors 12, 13, and 14, and first and third line conductors 15 and 16 connected to the first and third via conductors 12 and 14, respectively. The via conductors are disposed in a horizontal direction at predetermined intervals from each other with a

predetermined pattern in an insulator substrate (ceramic multilayer substrate) 11 composed of a laminate in which a plurality of insulator layers (for example, ceramic layers) 11A are laminated, and are extended inside the ceramic multilayer substrate 11 from the surface. The internal conductor electrically connects, for example, an integrated circuit (not shown in the drawing) mounted on the top surface of the ceramic multilayer substrate 11 to a mother board (not shown in the drawing) provided with the ceramic multilayer substrate 11.

As shown in Figs. 1(a) and 1(b), for example, the first and third via conductors 12 and 14 include first and third continuous via conductors 17 and 18, respectively, disposed extending in their respective directions farther from the adjacent second via conductor 13 and, in addition, the first and third via conductors 12 and 14 are connected to the first and third line conductors 15 and 16, respectively, through the first and third continuous via conductors 17 and 18, respectively. The first and third via conductors 12 and 14 are in no need of jutting from the first and third via conductors 12 and 14 toward the adjacent via conductor 13 to connect the first and third via conductors 12 and 14 to the first and third line conductors 15 and 16, respectively, through the first and third continuous via conductors 17 and 18, respectively. Therefore, the distance from the adjacent via conductor 13 can be decreased, so that the pitch can be reduced.

As shown in Fig. 1(b), the via conductors in the first line and the via conductors in the third line are vertically symmetric. The via conductors in the first line are assumed as fourth, fifth, and sixth via conductors 19, 20, and 21, and the via conductors in the third line are also assumed as fourth, fifth, and sixth via conductors 19, 20, and 21. The continuous via conductors extended from the fourth, fifth, and sixth via conductors 19, 20, and 21 are assumed as

fourth, fifth, and sixth continuous via conductors 22, 23, and 24, respectively. The line conductors connected to these continuous via conductors 22, 23, and 24 through connecting lands 25A, 26A, and 27A, respectively, are assumed as fourth, fifth, and sixth line conductors 25, 26 and 27, respectively. In Fig. 1(b), the first and third via conductors 12 and 14 and the fourth, fifth, and sixth via conductors 19, 20, and 21 are arranged to become vertically and bilaterally symmetric with respect to the second via conductor 13. The fourth, fifth, and sixth continuous via conductors 22, 23, and 24 are disposed extending in directions farther from the adjacent via conductors, and are connected to the fourth, fifth, and sixth line conductors 25, 26 and 27 at the ends of the extensions. A relationship among the fourth, fifth, and sixth via conductors 19, 20, and 21 is similar to the relationship among the first, second, and third via conductors 12, 13, and 14.

As shown in Fig. 1(b), the first and third continuous via conductors 17 and 18 and the fourth, fifth, and sixth continuous via conductors 22, 23, and 24 are disposed extending radially from the first and third via conductors 12 and 14 and the fourth, fifth, and sixth via conductors 19, 20, and 21 toward the outside centering the second via conductor 13. The direction of extension of the continuous via conductor is determined based on a pattern of via conductors and line conductors connected thereto. However, it is essential only that the continuous via conductor is disposed extending in a direction farther from an adjacent via conductor. In Fig. 1(a), the first and second continuous via 17 and 18 are formed in the same ceramic layer 11A. However, the interference between the line conductors can be prevented by forming the first and second continuous via 17 and 18 and the fourth, fifth, and sixth continuous via conductors 22, 23, and 24 in mutually different ceramic layers 11A depending on the wiring state of the line conductors. Therefore, the continuous via conductor can

be defined as a via conductor group in which a plurality of via conductors are successively disposed and continuously integrated in one insulator layer (for example, ceramic layer).

The extent to which the pitch in the internal conductor connection structure 10 of the present embodiment can be reduced in comparison with a known connection structure shown in Fig. 9 will be described taking the first and second via conductors 12 and 13 as examples with reference to Fig. 2. In the known connection structure, as shown in Fig. 2(b), a distance  $(M_1 + M_2 + G_1)$ , that is, the total sum of a jut dimension  $M_1$  of the connecting land 4 from the via conductor 2 required to connect reliably the via conductor 2 to the line conductor 3, a minimum dimension  $G_1$  required to avoid occurrence of short circuit and delamination between the connecting land 4 and the adjacent via conductor 2, and furthermore, a margin  $M_2$  required to ensure minimum gap even when a discrepancy between positions occurs, must be ensured between the adjacent via conductors 2 and 2. In general, this distance  $(M_1 + M_2 + G_1)$  must be on the order of 200  $\mu\text{m}$ . Consequently, it is difficult to reduce the pitch by decreasing the distance between the via conductors 2 and 2 to within 200  $\mu\text{m}$  in the known connection structure.

On the other hand, in the connection structure 10 of the present embodiment, a distance  $(M_3 + G_2)$ , that is, the total sum of a minimum dimension  $G_2$  required to avoid occurrence of short circuit and delamination between the first via conductor 12 and the adjacent second via conductor 13 and a margin  $M_3$  required to ensure the gap  $G_2$  even when a discrepancy of positions occurs between the first and second via conductors 12 and 13 must be required between the first and second via conductors 12 and 13 adjacent to each other. The dimension  $G_2$  in the connection structure 10 of the present embodiment and the dimension  $G_1$  in the known connection structure are substantially the same dimension. The margin  $M_3$  is determined based on the relationship

between the first via conductor 12 and the second via conductor 13. Since the first via conductor 12 to be connected to the first line conductor 15 and the second via conductor 13 disposed successively are processed in the same process, the factor of error is only a precision in via processing, and factors, such as elongation of the pattern during printing the line including the connecting land and an increase in working error resulting from undergoing two processes of the via processing and the printing of line, are eliminated, in contrast to the known connection structure shown in Fig. 2(b), so that the amount of discrepancy of the positions becomes small. Consequently, the present embodiment has a first advantage that the jut dimension  $M_1$ , which is required to ensure the reliability in connection, of the connecting land larger than the via diameter becomes unnecessary and a second advantage that the margin  $M_2$  is allowed to become small, while the margin  $M_2$  is necessary for preventing occurrence of short circuit and cracking (delamination) with respect to the adjacent first and second via conductors 12 and 13 when the discrepancy between positions occurs. Therefore, the distance between the first via conductor 12 and the second via conductor 13 in the present embodiment can be decreased to, for example, on the order of 100  $\mu\text{m}$ , that is, one-half the known distance, so that the pitch can be significantly reduced than ever.

As shown in Figs. 1(a) and (b), the first continuous via conductor 17 is formed to penetrate by one layer of the ceramic layer 11A, and four cylindrical conductors, each having the same diameter as that of the first via conductor 12, are successively formed in a horizontal direction while overlapping one another. The first continuous via conductor 17 can be formed into a substantially linear shape by filling a conductive paste in slim-shaped through holes composed of through holes overlapped one another and disposed in a ceramic green sheet (not shown in the drawing) by using a laser light or the like to

have the same diameter as that of the first via conductor 12, followed by sintering as a ceramic multilayer substrate, in the production of the ceramic multilayer substrate. The longitudinal side surface of this first continuous via conductor 17 is formed to be a concave and convex surface composed of linked arc-shaped surfaces. As shown in Fig. 1(b), the first line conductor 15 has a connecting land 15A serving as a connecting portion to the first continuous via conductor 17. This connecting land 15A is formed into a circular shape having an outer diameter larger than the outer diameter of an end portion of the extension of the first continuous via conductor 17. Therefore, even when a discrepancy occurs to some extent between the positions of the first line conductor 15 and the first via conductor 12, these two components 12 and 15 can be reliably connected through the first via conductor 17. Although the connecting land 15A has an outer diameter larger than the outer diameter of the first via conductor 12, since the connecting land 15A is located at a position farther from the second via conductor 13 than is the first via conductor 12, jutting from the first via conductor 12 toward the second via conductor 13 is unnecessary, and a reduction of pitch between the first and second via conductors 12 and 13 is not hindered.

In the internal conductor connection structure 10 of the present embodiment, the connecting land 15A is disposed on the first line conductor 15. However, the connecting land may be disposed on the continuous via conductor 17 side. In this case, for example, the connection structure can be realized by making the outer diameter of only a circular conductor farthest from the second via conductor 13 larger than the outer diameter of the first via conductor 12.

As described above, according to the present embodiment, in the internal conductor connection structure connecting the plurality of via conductors, first, second, and third via conductors 12, 13, and 14, adjacent to each other in the ceramic multilayer substrate 11 to the

first and third line conductors 15 and 16 disposed in the ceramic multilayer substrate 11, the first and third via conductors 12 and 14 connected to the first and third line conductors 15 and 16 include the first and third continuous via conductors 17 and 18 disposed extending in directions farther from the adjacent second via conductor 13, and the first and third via conductors 12 and 14 are connected to the first and third line conductors 15 and 16 through the first and third continuous via conductors 17 and 18. Consequently, the first and third via conductors 12 and 14 have no jut toward the second via conductor 13 side, the pitch between the first and third via conductors 12 and 14 and the second via conductor 13 can be reduced, and by extension, a high-density wiring can be realized in accordance with a reduction of pitch between external terminals of an integrated circuit.

Since the first via conductor 12 and the first line conductor 15 are connected through the end portion of extension of the first continuous via conductor 17, even when the connecting land 15A is disposed on the first line conductor 15, the connecting land 15A does not jut from the first via conductor 12 toward the second via conductor 13 side, and a discrepancy between positions of the first continuous via conductor 17 and the first line conductor 15 can be absorbed by the connecting land 15A in the production of the ceramic multilayer substrate 11, so that the first via conductor 12 and the first line conductor 15 can be connected reliably.

## SECOND EMBODIMENT

An embodiment of the multilayer substrate of the present invention will be described below with reference to Fig. 3 to Fig. 7. Since the multilayer substrate of the present embodiment is provided with the above-described internal conductor connection structure, the via conductors adjacent to each other will be described mainly.

As shown in Figs. 3(a) to 3(c), for example, the multilayer



substrate (for example, ceramic multilayer substrate) 30 of the present embodiment includes a laminate 31 in which a plurality of insulator layers (for example, ceramic layers) 31A are laminated, first, second, third, fourth, and fifth via conductors 32A, 32B, 32C, 32D, and 32E independently extending inside the laminate 31 from their respective positions at a predetermined interval (for example, 100  $\mu\text{m}$ ) from each other on one of main surfaces (top surface) of this laminate 31, and first, second, third, fourth, and fifth line conductors 33A, 33B, 33C, 33D, and 33E connected to first, second, third, fourth, and fifth via conductors 32A, 32B, 32C, 32D, and 32E, respectively. An integrated circuit 40 is mounted on the top surface of the laminate 31. For example, the first via conductor 32A and the second via conductor 32B are adjacent to each other as shown in Fig. 3(a). A plurality of external terminals (not shown in the drawing) of the integrated circuit 40 are electrically connected to the first to fifth via conductors 32A to 32E through solder balls 41. These via conductors 32A to 32E are connected to the line conductors 33A to 33E, respectively, with the same connection structure. Therefore, the first via conductor 32A and the first line conductor 33A will be described, while the other via conductors and line conductors are indicated only by reference numerals and the explanations thereof will not be provided. In the present embodiment, the external terminals of the integrated circuit 40 are connected directly to the first to fifth via conductors 32A to 32E exposed at the top surface of the laminate 31 without through any surface electrode (connecting pad). Consequently, application to the external terminals having a reduced pitch can be performed satisfactorily. If there is an allowance for space on the surface of the laminate 31, surface electrodes corresponding to the external terminals may be disposed on the top surface of the laminate 31, and via conductors may be connected to these surface electrodes. The alignment of the external terminals of

the integrated circuit 40 with the via conductors is facilitated by disposing the surface electrodes.

As shown in Fig. 3(a), the first via conductor 32A includes the first continuous via conductor 34A disposed extending in a direction farther from the adjacent second via conductor 32B (leftward in the drawing) and, in addition, the first via conductor 32A is connected to a first line conductor 33A through the first continuous via conductor 34A. The first continuous via conductor 34A and the first line conductor 33A are configured as in the connection structure 10 shown in Fig. 1. That is, in the first continuous via conductor 34A of the first via conductor 32A, cylindrical conductors are linearly arranged and integrated while overlapping one another and penetrating the ceramic layer 31A. In contrast to the connection structure 10 of the first embodiment, the first continuous via conductor 34A is disposed in such a way that the entirety is shifted in a direction farther from the second via conductor 32B. By shifting the first continuous via conductor 34A, even when a discrepancy between positions of the first continuous via conductor 34A and the first via conductor 32A occurs, the first continuous via conductor 34A is prevented from jutting toward the second via conductor 32B side. As shown in Figs. 3(b) and 3(c), a connecting land 15A having a diameter larger than the outer diameter of the cylindrical conductor is formed integrally on the connecting portion to the first continuous via conductor 34A of the first line conductor 33A. In the present embodiment, the first via conductor 32A and the first line conductor 33A are independently connected to the same surface (top surface) side of the first continuous via conductor 34A.

Fig. 4 is an exploded view showing a multilayer substrate 30 shown in Fig. 3 on a ceramic layer 31A basis. In Fig. 4, only those related to the first to fifth via conductors 32A to 32E in the second line are assigned reference numerals. As shown in Fig. 4, a plurality of lines

(three lines in Fig. 4) of the first to fifth via conductors 32A to 32E are disposed on the ceramic layer 31A serving as the first layer constituting the top surface of the laminate 31, and these via conductors 32A to 32E are arranged in the matrix as a whole. The first to fifth via conductors 32A to 32E, continuous via conductors 34A and 34E, and line conductors 33A and 33E are disposed on the ceramic layer 31A serving as the second layer. Only the second, third, and fourth via conductors 32B, 32C, and 32D are disposed on the ceramic layer 31A serving as the third layer. The second, third, and fourth via conductors 32B, 32C, and 32D and their respective continuous via conductors 34B, 34C, and 34D and line conductors 33B, 33C, and 33D are disposed on the ceramic layer 31A serving as the fourth layer. The continuous via conductors in every ceramic layer 31A are disposed extending in directions farther from adjacent via conductors. In Fig. 4, portions having large outer diameters at the connecting portions of the via conductors and the line conductors are connecting lands of the line conductors.

In the case where the adjacent first and second via conductors 32A and 32B are connected to the first line conductor 33A and the second line conductor (the second line conductor is not shown in the drawing), respectively, through the first and second continuous via conductors 34A and 34B, respectively, as shown in Fig. 3(a), the first and second continuous via conductors 34A and 34B can be disposed in mutually different ceramic layers 31A and 31A laminated and, thereby, interference between the line conductors can be prevented, so that the via conductors can be arranged densely.

Preferably, for example, a low-temperature sinterable ceramic material is used as the material for forming the ceramic layer 31A. The low-temperature sinterable ceramic material refers to a material that can be sintered at a firing temperature of, for example, 1,000°C or less, and can be co-sintered with a low-melting point metal, e.g.,

Ag or Cu. Examples of low-temperature sinterable ceramic materials may include glass composite materials formed by mixing borosilicate glass into ceramic powders, e.g., alumina and forsterite, crystallized glass materials through the use of ZnO-MgO-Al<sub>2</sub>O<sub>3</sub>-SiO<sub>2</sub> crystallized glass, and non-glass materials through the use of BaO-Al<sub>2</sub>O<sub>3</sub>-SiO<sub>2</sub> ceramic powders, Al<sub>2</sub>O<sub>3</sub>-CaO-SiO<sub>2</sub>-MgO-B<sub>2</sub>O<sub>3</sub> ceramic powders, and the like.

Electrically conductive materials having small resistivities may be used as the via conductors, the continuous via conductors, and the line conductors. Preferably, for example, an electrically conductive material primarily containing Ag or Cu that can be sintered simultaneously with a low-temperature sinterable ceramic material is used as the electrically conductive material. The conductors primarily containing Ag or Cu has a small electrical resistance and, therefore, has an advantage in the use of the ceramic multilayer substrate 30 as a high-frequency component.

A method for manufacturing the ceramic multilayer substrate 30 of the present embodiment will be described below.

A low-temperature sinterable ceramic material is dispersed in a vinyl alcohol based binder to prepare a slurry. The resulting slurry is applied to a carrier film by a doctor blade method or the like, so that a ceramic green sheet for low temperature sintering is prepared. The ceramic green sheet is cut into a predetermined size.

Laser light (for example, CO<sub>2</sub> laser light) with a controlled output is applied from the carrier film side, the carrier film and the ceramic green sheet are penetrated, so that through holes used for via conductors are formed in both of them. In the case where through holes used for continuous via conductors are formed in the ceramic green sheet, the laser light is moved by the predetermined dimension to form successively, for example, four through holes communicated to one another. At this time, the laser light is moved in such a way that through holes are overlapped one another. When the strength of

the carrier film is inadequate, an weakly adhesive film (for example, a PET film coated with about 10  $\mu\text{m}$  of acrylic adhesive) may be attached to a ceramic green sheet surface to hold the ceramic green sheet, and laser light may be applied to penetrate the carrier film, ceramic green sheet, and the weakly adhesive film, so that the through holes may be formed.

Subsequently, a conductive paste is filled in through holes from the carrier film side, and an excess conductive paste is removed from the carrier film. When the conductive paste is filled in the through holes, the ceramic green sheet may be placed on a support table with a suction mechanism, a negative pressure may be formed in the through holes and, thereby, the conductive paste may be reliably filled in the through holes. When the weak adhesive film is used, the weak adhesive film is peeled off the ceramic green sheet after the conductive paste is dried.

A predetermined pattern of the conductive paste is applied by screen printing to the ceramic green sheet on the carrier film, so that a wiring pattern for the line conductors having connecting lands is formed.

After the required number of ceramic green sheets filled in and coated with the conductive paste for the via conductors, continuous via conductors, and the line conductors are produced in the above-described procedure, these ceramic green sheets are laminated and pressure-bonded at a predetermined pressure, so that a green laminate is produced. At this time, even when a discrepancy occurs between positions of the portions filled in with the conductive paste for the via conductors and the wiring pattern for the line conductors resulting from working errors, discrepancies in lamination, and the like, this discrepancy between positions can be absorbed by the connecting lands. Therefore, the portions filled in with the conductive paste for the via conductors including the continuous via

conductors and the wiring pattern for the line conductors can be connected reliably.

Thereafter, parting lines to divide into individual ceramic multilayer substrates are formed on the surface of the green laminate. The green laminate is fired at a predetermined temperature of 1,000°C or less to produce a sintered material. The sintered material is subjected to a plating treatment, the resulting sintered material is divided, so that a plurality of ceramic multilayer substrates of the present embodiment can be produced.

As described above, according to the present embodiment, the laminate 31 in which a plurality of ceramic layers 31A are laminated, the first and second via conductors 32A and 32B independently extending inside the laminate 31 from their respective positions adjacent to each other at a predetermined interval on the top surface of this laminate 31, and the first line conductor 33A connected to the first via conductor 32A are included. The first via conductor 32A includes the first continuous via conductor 34A disposed extending in a direction farther from the second via conductor 32B and, in addition, the first via conductor 32A is connected to the first line conductor 33A through the first continuous via conductor 34A. That is, the connection structure of the first via conductor 32A and the first line conductor 33A has the same configuration as the above-described internal conductor connection structure 10. Therefore, the pitch between the first and second via conductors 32A and 32B can be reduced in conformity with the external terminals of the integrated circuit 40. The above-described relationship holds between other adjacent via conductors, for example, the second via conductor 32B and the third via conductor 32C, and a reduction of pitch between via conductors in every direction can be realized. Consequently, the ceramic multilayer substrate 30 of the present embodiment can realize a high-density wiring in conformity with the integrated circuit 40.

According to the present embodiment, for example, since the first and second continuous via conductors 34A and 34B of the adjacent first and second via conductors 32A and 32B are disposed in different ceramic layers 31A and 31A, the first and second continuous via conductors 34A and 34B do not interfere with each other, and can reliably be formed in directions farther from the second and third via conductors 32B and 32C, respectively, adjacent thereto.

### THIRD EMBODIMENT

A ceramic multilayer substrate of the present embodiment is configured in conformity with the ceramic multilayer substrate 30 in the second embodiment except that the forms of a continuous via conductor and a line conductor are different from those of the ceramic multilayer substrate 30 in the second embodiment. Therefore, the same components as or components corresponding to those of the ceramic substrate 30 in the second embodiment are indicated by the same reference numerals as in the second embodiment, and only feature components of the present embodiment will be described.

In the present embodiment, as shown in Figs. 5(a) to 5(c), a connecting land 36A is disposed at the connecting portion (end portion of extension) of the first continuous via conductor 34A to the first line conductor 33A in place of the connecting land 35A of the first line conductor 33A in the second embodiment. This connecting land 36A is formed from a cylindrical conductor having a diameter larger than the outer diameter of the first via conductor 32A and the width of the first line conductor 33A. The other cylindrical conductors of the first continuous via conductor 34A are formed to have the same outer diameter as that of the first via conductor 32A. In the present embodiment as well, the operation and the effect similar to those in the second embodiment can be expected. In the present embodiment, the first line conductor 33A is connected to a surface of the first continuous via conductor 34A, the surface opposite to the surface on

which the first via conductor 32A is disposed.

#### FOURTH EMBODIMENT

A ceramic multilayer substrate of the present embodiment is configured in conformity with the ceramic multilayer substrate 30 in the second embodiment except that the form of a continuous via conductor is different from that of the ceramic multilayer substrate 30 in the second embodiment. Therefore, the same components as or components corresponding to those of the ceramic substrate 30 in the first embodiment are indicated by the same reference numerals, and only feature components of the present embodiment will be described.

In the present embodiment, as shown in Fig. 6, a first continuous via conductor 34A does not penetrate a ceramic layer 31A, and is formed by filling in a concave portion formed in the ceramic layer 31A. A first line conductor 33A is connected to the top surface of the first continuous via conductor 34A. The first line conductor 33A has a connecting land as in the second embodiment. The output of laser light is reduced than that in the second embodiment in order that the laser light does not penetrate the ceramic green sheet. The laser light is applied to the ceramic green sheet and, thereby, a concave portion can be formed in the ceramic green sheet. This concave portion is filled in with a conductive paste, followed by firing, so that the first continuous via conductor 34A shown in Fig. 6 can be produced. In the present embodiment, since the conductive paste is filled in the concave portion, leakage of the conductive paste can be prevented, and a highly reliable via conductor can be produced. Since the first continuous via conductor 34A does not penetrate the ceramic layer 31A, even when line conductors 33X are disposed at the positions overlapping the first continuous via conductor 34A, as shown in Fig. 6, the first via conductor 32A and the line conductor 33X are not brought into contact with each other. Therefore, in contrast to the first to third embodiments, it is not necessary to interpose a ceramic green



sheet with no print therebetween during production, so that the thickness of the laminated layer 31 can be decreased, and slimming of the ceramic multilayer substrate 30 can be facilitated. Even in the case where a ceramic green sheet is interposed, the sheet thickness can be decreased and, by extension, slimming can be facilitated. In addition, the operations and the effects similar to those in the second and third embodiments can be expected.

For example, as shown in Fig. 7, the ceramic multilayer substrates 30 of the second to fourth embodiments can be mounted on a mother board 50. In this case, the via conductor 32 exposed at the bottom surface of the laminate 31 is connected to a terminal electrode 51 of the mother board 50 through solder. The exposed via conductor 32 may be connected directly to the terminal electrode 51 of the mother board 50 without through any surface electrode (connecting pad), and it is possible to cope with a reduction of the pitch between the terminal electrodes 51. Therefore, high density mounting of the ceramic multilayer substrate 30 on the mother board can be performed, while active components, e.g., integrated circuits, and passive components, e.g., chip type ceramic electronic components, are installed on the top surface of the ceramic multilayer substrate 30.

#### FIFTH EMBODIMENT

A ceramic multilayer substrate of the present embodiment is configured in conformity with the ceramic multilayer substrate 30 in the second embodiment except that the insulator layer (for example, ceramic layer) including a continuous via conductor is formed to have a thickness smaller than the thicknesses of the other insulator layers. Therefore, the same components as or components corresponding to those of the ceramic substrate 30 in the second embodiment are indicated by the same reference numerals as in the second embodiment, and only feature components of the present embodiment will be described.

In the present embodiment, as shown in Fig. 8, a ceramic layer

31'A provided with a first continuous via conductor 34A is formed to have a thickness smaller than the thicknesses of the other ceramic layers 31A. This first continuous via conductor 34A is formed to penetrate the ceramic layer 31'A as in the first to third embodiments. Furthermore, when line conductors 33X are disposed at positions overlapping this first continuous via conductor 34A, as shown in Fig. 8, the ceramic layer 31'A thinner than the other ceramic layers 31A is interposed between the two components, 34A and 33X. By such a configuration, the laminate 31 can be made a thinner layer as compared with those in the first to third embodiments, and slimming of the ceramic multilayer substrate 30 can be facilitated. In addition, the control of the laser light output becomes unnecessary as compared with the fourth embodiment.

That is, in the first to third embodiments, the first continuous via conductor 34A penetrates the ceramic layer 31A. Therefore, in the case where the line conductors 33X are disposed at positions overlapping the first continuous via conductor 34A, a ceramic green sheet with no print must be interposed in order to avoid contact with the first continuous via conductor 34A, so that the ceramic multilayer substrate 30 becomes thick by the thickness of the ceramic layer with no print. In the fourth embodiment, since the first continuous via conductor 34A does not penetrate the ceramic layer 31 and, therefore, is of non-penetration type, the laser light output must be controlled when the concave portion for the first continuous via conductor 34A is disposed. On the other hand, in the fifth embodiment, the inconveniencies in the first to fifth embodiments can be eliminated.

In each of the above-described embodiments, the case where the continuous via conductor is connected to the line conductor is explained. However, the continuous via conductor according to the present invention can also be used in the case where via conductors are connected to each other in place of the line conductor. When the

via conductors are arranged in the matrix, and the via conductors to be connected to each other are arranged while being sandwiched from both sides by other via conductors, they can be connected reliably by connecting the two through the use of the continuous via conductor. The through holes for the continuous via conductor are disposed in the stage of formation of the through holes for via conductors and, therefore, can be precisely formed without an occurrence of discrepancy between positions resulting from, for example, printing of line conductors. In the case where the via conductors are connected to each other with the line conductor, a discrepancy in printing of the line conductors and a discrepancy between positions of the via conductors and the line conductors in the lamination stage of the ceramic green sheets tend to occur. Furthermore, since the line conductor includes the connecting land, if a discrepancy between positions of the line conductor and the via conductor occurs, the via conductors and the connecting land sandwiching these via conductors may be brought close or into contact. Even when the connection is established, short circuit may occur between the connecting land and adjacent via conductors.

The present invention is not limited to each of the above-described embodiments. For example, in the case where the continuous via conductor is of the type of penetrating the ceramic layer, a leakage of conductive paste can reliably be prevented by forming each cylindrical conductor of the continuous via conductor into the shape of an inverted truncated cone, put another way, by forming the through hole for each cylindrical conductor disposed in the ceramic green sheet into the shape of an inverted truncated cone.

#### Industrial Applicability

The present invention is suitable for use as a multilayer substrate serving for mounting various chip type electronic components.